

RJK0602DPN-E0

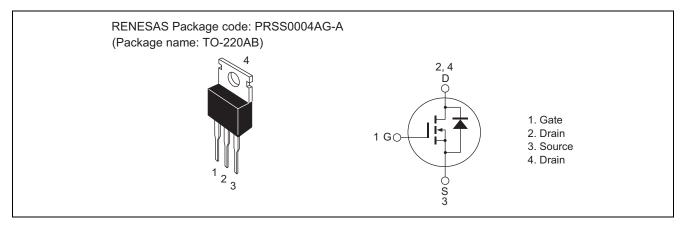
N-Channel MOS FET 60 V, 100 A, 3.9 m Ω

R07DS0653EJ0200 Rev.2.00 Aug 24, 2012

Features

- High speed switching
- Low drive current
- Low on-resistance $R_{DS(on)} = 3.1 \text{ m}\Omega \text{ typ.}$ (at $V_{GS} = 10 \text{ V}$)
- Package TO-220AB

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$	
Item	Symbol	Ratings	Unit	
Drain to source voltage	V _{DSS}	60	V	
Gate to source voltage	V _{GSS}	±20	V	
Drain current	I _D	100	А	
Drain peak current	I _{D (pulse)} Note1	300	А	
Body-drain diode reverse drain current	I _{DR}	100	А	
Avalanche current	I _{AP} Note2	50	А	
Avalanche energy	E _{AS} Note2	188	mJ	
Channel dissipation	Pch Note3	150	W	
Channel to case thermal impedance	θch-c	0.83	°C/W	
Channel temperature	Tch	150	٥°	
Storage temperature	Tstg	-55 to +150	°C	

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at L = 100 μH , Tch = 25°C, Rg $\geq 50 \Omega,$

3. Tc = 25°C



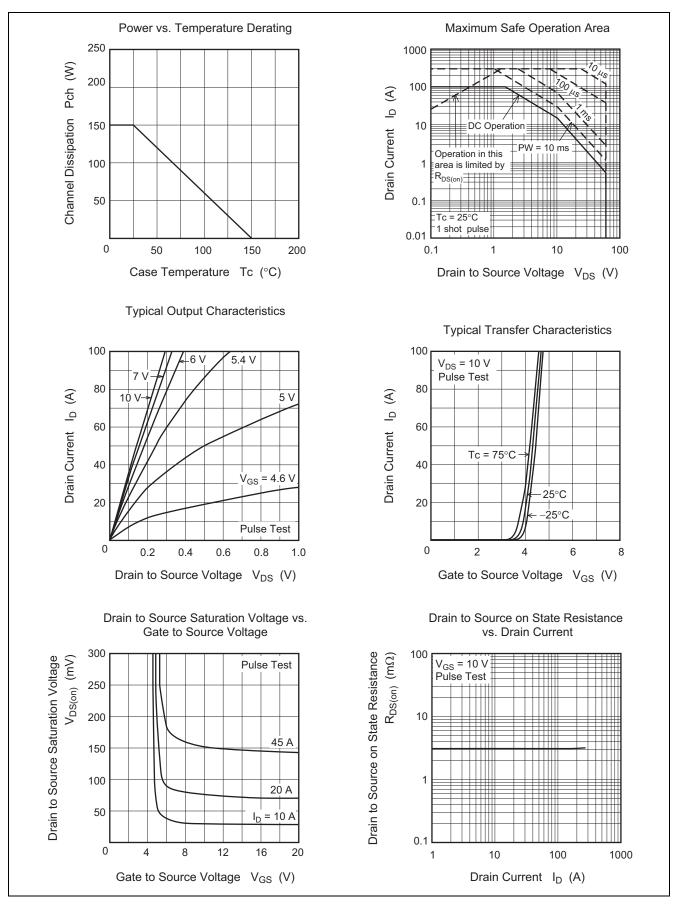
Electrical Characteristics

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V _{(BR)DSS}	60	—	_	V	$I_D = 10mA, V_{GS} = 0$
Gate to source leak current	I _{GSS}	—	—	±0.1	μA	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	—	1	μA	$V_{DS} = 60 V, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	2.0	—	4.0	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	—	3.1	3.9	mΩ	I_D = 50 A, V_{GS} = 10 V ^{Note4}
resistance	by 1	_	100		S	$I_D = 50 \text{ A}, V_D = 10 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}				-	
Input capacitance	Ciss	_	6450	—	pF	V _{DS} = 10 V V _{GS} = 0 f = 1 MHz
Output capacitance	Coss	—	1400		pF	
Reverse transfer capacitance	Crss	—	330	—	pF	
Gate Resistance	Rg	_	1.5	—	Ω	
Total gate charge	Qg	—	90	_	nC	V_{DD} = 25 V V_{GS} = 10 V, I_{D} = 50 A
Gate to source charge	Qgs	—	33	_	nC	
Gate to drain charge	Qgd	—	16	_	nC	
Turn-on delay time	t _{d(on)}	—	40	—	ns	$\label{eq:VGS} \begin{array}{l} V_{GS} = 10 \ V \\ I_D = 50 \ A \\ V_{DD} \cong 30 \ V \\ Rg = 4.7 \ \Omega \end{array}$
Rise time	tr	—	15	—	ns	
Turn-off delay time	t _{d(off)}	—	70	—	ns	
Fall time	t _f	_	17	—	ns	
Body-drain diode forward voltage	V _{DF}	_	0.85	1.5	V	$I_F = 100 \text{ A}, V_{GS} = 0^{Note4}$
Body-drain diode reverse recovery time	t _{rr}	_	60	—	ns	$I_F = 100 \text{ A}, V_{GS} = 0$
						di _F /dt = 100 A/μs

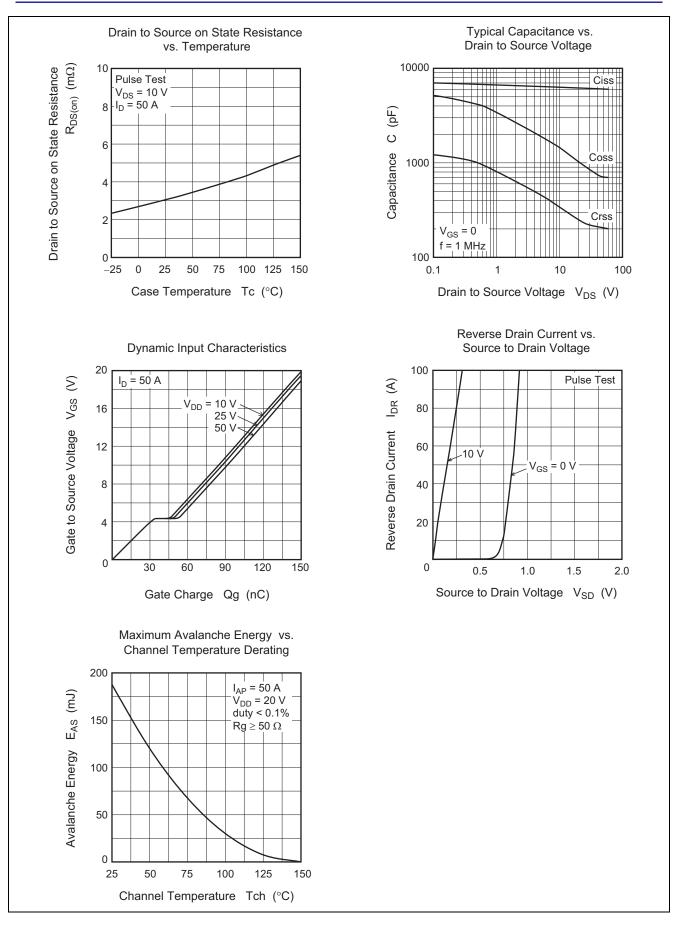
Notes: 4. Pulse test

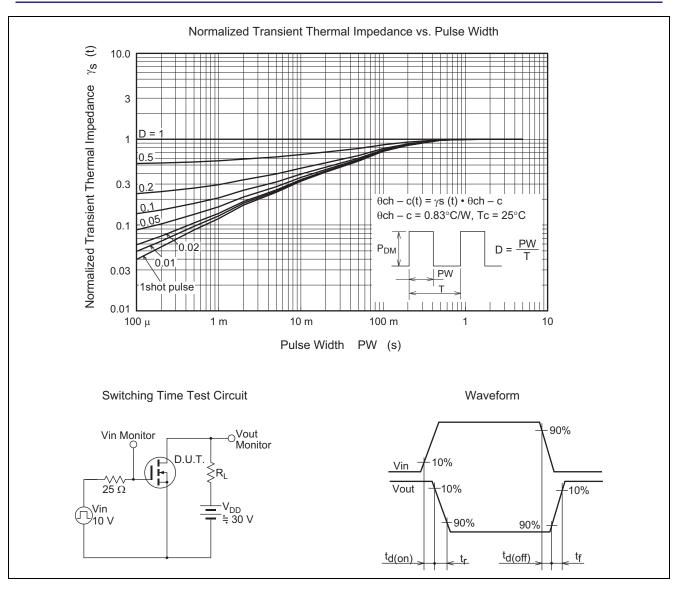


Main Characteristics



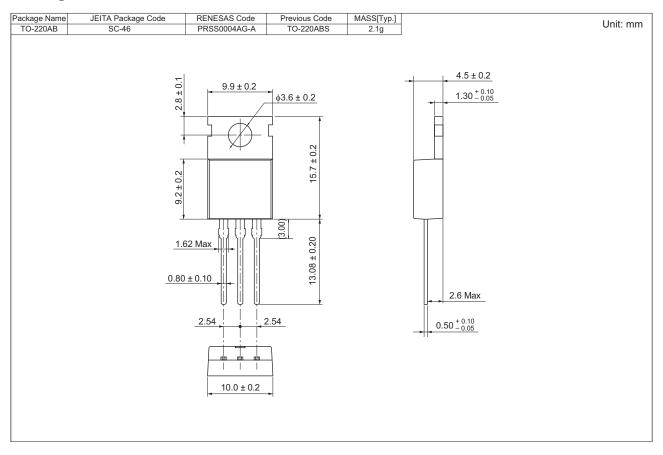








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK0602DPN-E0-T2	50 pcs	Magazine (Tube)

Note: The symbol of 2nd "-" is occasionally presented as "#".



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Renesas Electronics Corporation

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Renesas Electronics America Inc.

2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A.

Tel: +1-408-588-000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited

101 Nicholson Road, Newmarkst, Ontario L3Y 9C3, Canada

Tel: +1-905-9898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited

Dukes Meadow, Millocard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K

Tel: +49-211-65030, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany

Tel: +92-211-65030, Fax: +449-211-6503-1327

Renesas Electronics (Shanghal) Co., Ltd.

7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China

Tel: +86-21-657-1518, Fax: +86-21-08235-7679

Renesas Electronics (Shanghal) Co., Ltd.

Unit 204, 205, AZIA Center, No.1233 Lujiazu Ring Rd., Pudong District, Shanghai 200120, China

Tel: +86-27-8587-7858 / -7889

Renesas Electronics Taiwan Co., Ltd.

Unit 1001-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong

Tel: +85-2886-9318, Fax: +852 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd.

137, No. 33, Fu Shing North Road, Taipei, Taiwan

Tel: +85-24175-9900, Fax: +8862 24175-9907

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